

SANYO**LA7411,7411M****Playback Amplifier and Record Amplifier
for VHS VCRs****Overview**

The LA7411 and LA7411M are playback and record amplifier IC for two-head VHS VCRs. When used in conjunction with the video signal processing ICs of the LA7420/30 series, it is possible to eliminate the need to adjust the Y/C record current.

Functions

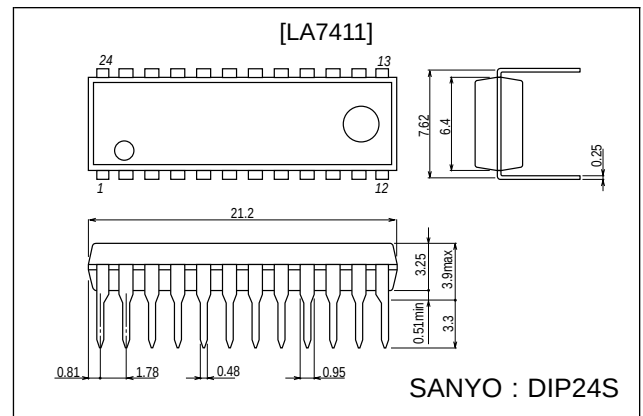
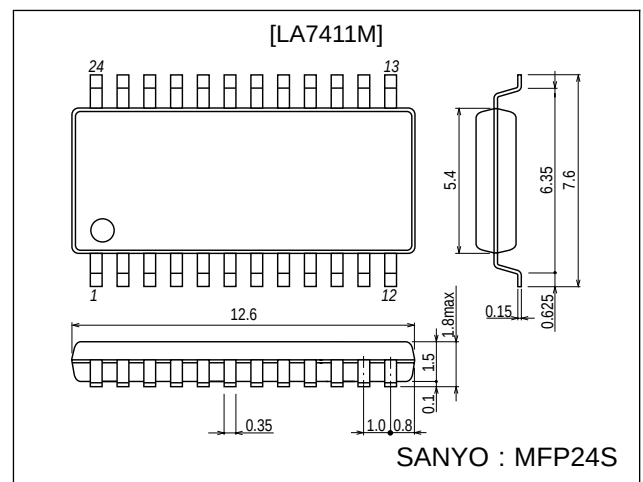
- 2-channel playback amplifier.
- 1-channel record amplifier.
- REC/PB mode switching head switch circuit.
- Envelope wave detection (for auto-tracking).

Features

- The record amplifier provides stable record characteristics in constant current drive mode, which is able to withstand load fluctuations. In addition, the built-in AGC eliminates the need to adjust the record current.
- Designed to share printed circuit boards with the LA7416/7416M (for 4-head systems).

Package Dimensions

unit : mm

3067-DIP24S**3112-MFP24S**

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Specifications

Maximum Ratings at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 65 °C	700	mW
			*500	mW
Operating temperature	T _{opr}		−10 to +65	°C
Storage temperature	T _{stg}		−40 to +150	°C

*: LA7411M Pd max value which represents the value when mounted on the board.

Operating Conditions at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		5.0	V
Operating supply voltage range	V _{CC} op		4.8 to 5.5	V

Electrical Characteristics at Ta = 25 °C

Parameter	Symbol	Input	Output	Conditions	T1	T2	min	typ	max	Unit
[PB Mode]				T12: 5.0 V T10: Open T4: Open (PB)	EP/SP	SW30 MUTE				
Current consumption	I _{CCP}			Pin 12 input current		0	14	18	22	mA
Voltage gain L	CH1	G _{VP1}	T17A	T7A	V _I = 38 mVp-p f = 1 MHz	0	56.5	59.5	62.5	dB
Voltage gain H	CH2	G _{VP2}	T20A	T7A		2.5	56.5	59.5	62.5	dB
Voltage gain difference		ΔG _{VP1}			G _{VP1} — G _{VP2}		−1	0	+1	dB
Equivalent input noise voltage	CH1	V _{NIN1}	T17A	T7A	After 1.1 MHz LPF V _{OUT} /G _{VP1,2}	0		1.1	1.5	μVrms
	CH2	V _{NIN2}	T20A	T7A		2.5		1.1	1.5	μVrms
Frequency characteristics	CH1	ΔV _{fp1}	T17A	T7A	V _I = 38 mVp-p, f = 7 MHz V _{OUT} /G _{VP1,2} output ratio	0	−2.5	+1		dB
	CH2	ΔV _{fp2}	T20A	T7A		2.5	−2.5	+1		dB
Secondary harmonic distortion	CH1	V _{HDP1}	T17A	T7A	V _I = 38 mVp-p, f = 4 MHz 8 M component 4 M component output ratio	0		−40	−35	dB
	CH2	V _{HDP2}	T20A	T7A		2.5		−40	−35	dB
Maximum output level	CH1	V _{OMP1}	T17A	T7A	f = 1 MHz Output level when tertiary distortion of the output is −30 dB	0	1.0	1.2		Vp-p
	CH2	V _{OMP2}	T20A	T7A		2.5	1.0	1.2		Vp-p
Cross-talk (Note 1)	CH1	V _{CR1}	T20A	T7A	V _I = 38 mVp-p, f = 4 MHz V _{OUT} /G _{VP1,2} output ratio	0		−40	−35	dB
	CH2	V _{CR2}	T17A	T7A		2.5		−40	−35	dB
Output DC offset	ΔV _{ODC1}		T7	CH1–CH2		0	−100	0	+100	mV
						2.5				
Envelope wave detection output pin voltage	V _{ENV}		T5	T5 DC voltage with no input	0	0	0	0.8	1.5	V
Envelope wave detection voltage SP1	V _{ENVSP1}	T17A	T5	f = 4 MHz, T7A: Adjusted to 175 mVp-p	0	0	2.0	2.5	3.0	V
Envelope wave detection voltage SP2	V _{ENVSP2}	T17A	T5	f = 4 MHz, T7A: Adjusted to 450 mVp-p	0	0	4.5	4.8	5.0	V
Envelope wave detection voltage EP1	V _{ENVEP1}	T17A	T5	f = 4 MHz, T7A: Adjusted to 125 mVp-p	5.0	0	2.0	2.5	3.0	V

Note 1: Status where input stage L (8.2 μH) is shorted

“*” represents output pins.

Electrical Characteristics at Ta = 25 °C

Parameter	Symbol	Input	Output	Conditions	T10	T2	min	typ	max	Unit
Envelope wave detection voltage EP2	V _{ENVEP2}	T17A	T5	f = 4 MHz, T7A: Adjusted to 350 mVp-p	5.0	0	4.5	4.8	5.0	V
ON resistance of SW-Tr which is turned ON in PB mode	R _{PON14}		P-14	DC difference measured for 1 mA, 2 mA current inflow				4.0	6.0	Ω
Threshold level EP/SP	EPS-1		T1	SP → EP	*		1.7		5.0	V
	EPS-2		T1	EP → SP	*		0.0		1.3	V
Threshold level SW30	SW30-1		T2	Lch → Hch		*	1.2		5.0	V
	SW30-2		T2	Hch → Lch		*	0.0		0.8	V
[REC Mode]				T12: 5.0 V T3: 5.0 V T4: 5.0 V(REC)	REC Adj2	SW30 MUTE				
Current consumption	I _{CCP}			Pin 12 input current	Open	0	38	46	54	mA
REC AGC Amp output level	V _R	T8A	T18A	f = 4 MHz V _I = 200 mVp-p	Open	0	116	123	130	mVp-p
AGC Amp control characteristics 1	ΔV _{AGC1}	T8A	T18A	f = 4 MHz, V _I = 400 mVp-p Output level/ V _{RSP, EP} ratio	Open	0		0.5	1.0	dB
AGC Amp control characteristics 2	ΔV _{AGC2}	T8A	T18A	f = 4 MHz, V _I = 100 mVp-p Output level/ V _{RSP, EP} ratio	Open	0	-1.0	-0.5		dB
AGC Amp frequency characteristics (Note 2)	ΔV _{FR}	T8A	T18A	f = 1 M, 7 MHz V _I = 200 mVp-p 7 MHz/1 MHz, output ratio	Open	0	-4.0	-3.0	-2.0	dB
AGC Amp secondary harmonic level	ΔV _{HDR}	T8A	T18A	f = 4 MHz, V _I = 200 mVp-p 8 M component 4 M component output ratio	Open	0		-45	-40	dB
AGC Amp maximum output level (Note 3)	ΔV _{OMR}	T8A	T18A	f = 4 MHz, output level when secondary distortion of the output is -35 dB	Adj.	0	20	22		mAp-p
AGC Amp mute attenuation	ΔV _{MR}	T8A	T18A	f = 4 MHz, V _I = 200 mVp-p Output level/ V _{RSP, EP} ratio	Open	5.0		-45	-40	dB
REC AGC Amp mixed modulation relative level	ΔV _{CY}	T7A	T18A	T6A: f = 629 kHz, V _I = 360 mVp-p T7A: f = 4 MHz, V _I = 200 mVp-p (4 M±629 k)/4 M output ratio	Open	0		-45	-40	dB
		T8A	T18A		Open	0		-45	-40	dB
ON resistance of SW-Tr which is turned ON in REC mode	R _{RON17}		P-17	DC difference measured for 1 mA, 2 mA current inflow				4.0	6.0	Ω
	R _{RON20}		P-20					4.0	6.0	Ω
REC MUTE threshold level	MUTE-1		T2	MUTE OFF → ON		*	3.4		5.0	V
	MUTE-2		T2	MUTE ON → OFF		*	0.0		3.0	V
REC/PB threshold level	SW REC/PB			T4: Control voltage			2.2		5.0	V

Note 2: Apply approximately 1.8 V DC to the AGC wave detection filter pin (pin 9) and fix the amplifier gain for measurement.

Note 3: Apply DC voltage to T10 (REC CUR. ADJ2) and adjust the output level.

Note : Use a resistor with a tolerance of ± 1.0% between pins 11 and 12.

“*” represents output pins.

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